

# 3.0 GHz Medium Power Silicon RFIC Amplifier

## Technical Data

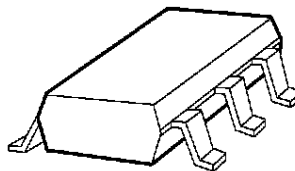
### Features

- +8 dBm  $P_{1\text{ dB}}$  at 1.9 GHz
- 21 dB Gain at 1.9 GHz
- High Isolation 32 dB at 1.9 GHz
- Single +3V Supply
- Unconditionally Stable

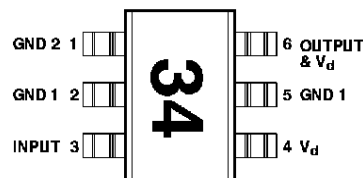
### Applications

- LO Buffer and Driver Amplifier for Cellular, Cordless, Special Mobile Radio, PCS, ISM, Wireless LAN, DBS, TVRO, and TV Tuner

### Surface Mount SOT-363 (SC-70) Package



### Pin Connections and Package Marking



Note: Package marking provides orientation and identification.

### INA-34063

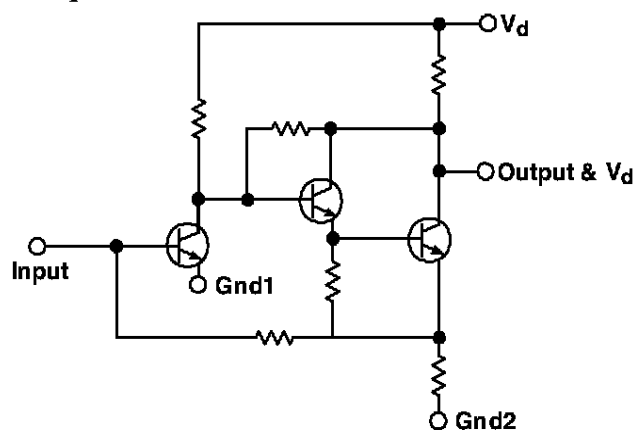
### Description

Hewlett-Packard's INA-34063 is a Silicon RFIC amplifier that offers excellent gain and output power for applications to 3.0 GHz. Packaged in an ultraminiature SOT-363 package, it requires half of the board space of a SOT-143 package.

With its wide bandwidth and high linearity, the INA-34063 is suitable as a driver amplifier for various applications. The INA-34063 also features high reverse isolation, making it an excellent candidate for LO buffer applications.

The INA-34063 is fabricated using HP's 30 GHz- $f_{\text{max}}$ , ISOSAT™ Silicon-bipolar process that uses nitride, self-alignment, submicrometer lithography, trench isolation, ion implantation, and polyimide intermetal dielectric and scratch protection to achieve superior performance, uniformity and reliability.

### Simplified Schematic



## Absolute Maximum Ratings

Symbol	Parameter	Units	Absolute Maximum <sup>[1]</sup>
$V_d$	Device Voltage, RF output to ground	V	6.0
$P_{in}$	CW RF Input Power	dBm	+7.0
$T_j$	Junction Temperature	°C	150
$T_{SRG}$	Storage Temperature	°C	-65 to 150

### Thermal Resistance<sup>[2]</sup>:

$$\theta_{jc} = 170^{\circ}\text{C/W}$$

#### Notes:

1. Operation of this device above any one of these limits may cause permanent damage.
2.  $T_C = 25^{\circ}\text{C}$  ( $T_C$  is defined to be the temperature at the package pins where contact is made to the circuit board)

## INA-34063 Electrical Specifications, $T_C = 25^{\circ}\text{C}$ , $Z_0 = 50\ \Omega$ , $V_d = 3\ \text{V}$

Symbol	Parameters and Test Conditions	Units	Min.	Typ.	Max.	Std. Dev. <sup>[4]</sup>
$ S_{21} ^2$	Gain in 50 $\Omega$ system  f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dB	18.0 <sup>[3]</sup>	20.1 21.4 20.6		0.39
$NF_{50}$	Noise Figure  f = 1.9 GHz	dB		4.5		0.19
$P_{1dB}$	Output Power at 1 dB Gain Compression  f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dBm		7.8 8.2 6.5		
$IP_3$	Output Third Order Intercept Point  f = 0.9 GHz f = 1.9 GHz f = 2.4 GHz	dBm		19.4 18.0 15.6		
$VSWR_{in}$	Input VSWR  f = 0.1 – 2.4 GHz			1.35:1		
$VSWR_{out}$	Output VSWR  f = 0.1 – 2.4 GHz			1.10:1		
$I_d$	Device Current	mA		30	37 <sup>[3]</sup>	0.9

#### Notes:

3. Guaranteed specifications are 100% tested in production.
4. Standard deviation number is based on measurement of a large number of parts from three non-consecutive wafer lots during the initial characterization of this product, and is intended to be used as an estimate for distribution of the typical specification.

# INA-34063 Typical Performance, $T_C = 25^\circ\text{C}$ , $Z_O = 50\ \Omega$ , $V_d = 3\ \text{V}$

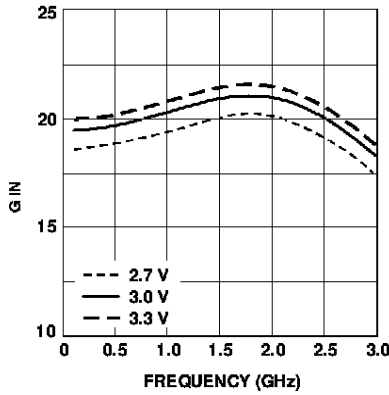


Figure 1. Gain vs. Frequency and Voltage.

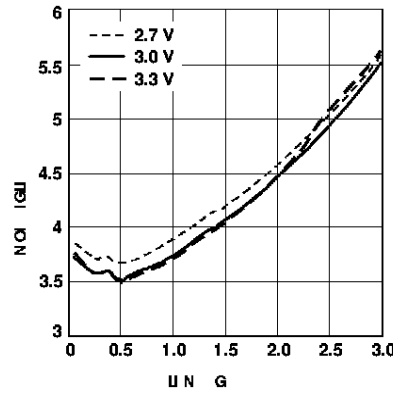


Figure 2. Noise Figure vs. Frequency and Voltage.

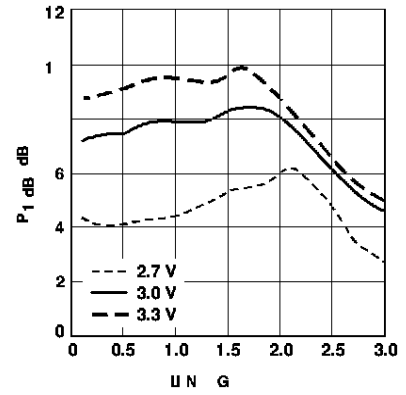


Figure 3. Output Power for 1 dB Gain Compression vs. Frequency and Voltage.

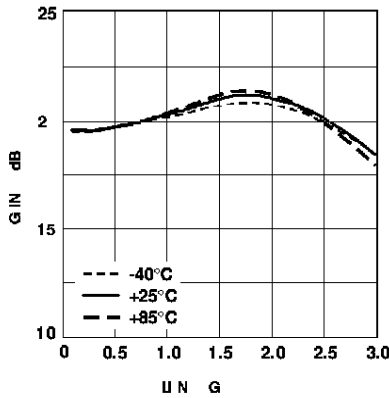


Figure 4. Gain vs. Frequency and Temperature.

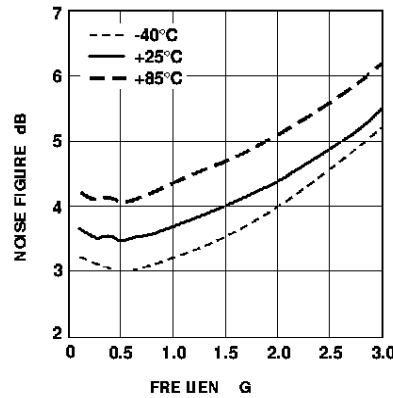


Figure 5. Noise Figure vs. Frequency and Temperature.

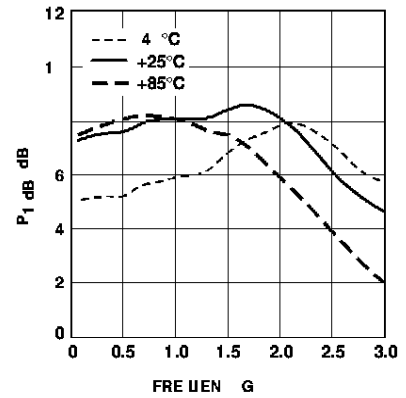


Figure 6. Output Power for 1 dB Gain Compression vs. Frequency and Temperature.

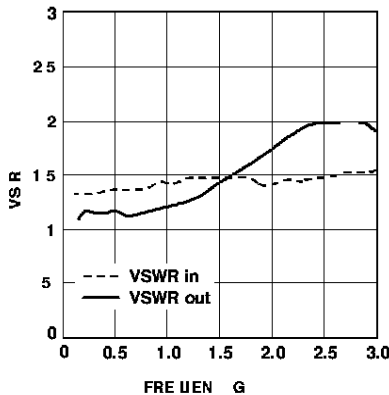


Figure 7. Input and Output VSWR vs. Frequency.

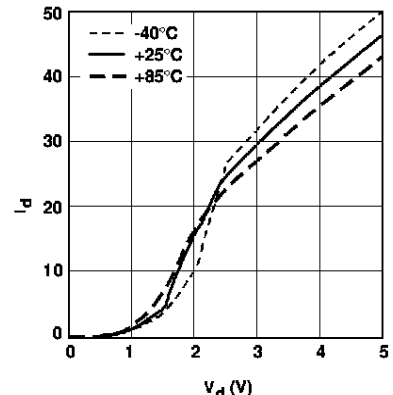


Figure 8. Supply Current vs. Voltage and Temperature.

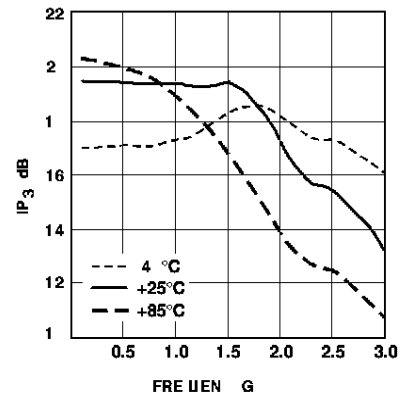


Figure 9. Third Order Intercept Point,  $IP_3$  vs. Frequency and Temperature.

**INA-34063 Typical Scattering Parameters<sup>[5]</sup>,  $T_C = 25^\circ\text{C}$ ,  $Z_O = 50\ \Omega$ ,  $V_d = 3.0\ \text{V}$** 

Freq. GHz	$S_{11}$		dB	$S_{21}$		dB	$S_{12}$		$S_{22}$		K Factor
	Mag	Ang		Mag	Ang		Mag	Ang	Mag	Ang	
0.1	0.14	2	19.3	9.23	-4	-28.0	0.040	1.65	0.049	-42	1.50
0.2	0.14	3	19.3	9.26	-9	-28.9	0.036	-1	0.085	-24	1.61
0.3	0.14	2	19.4	9.30	-13	-28.7	0.037	-5	0.070	-26	1.58
0.4	0.15	2	19.4	9.38	-17	-29.2	0.035	-10	0.089	-16	1.62
0.5	0.15	4	19.5	9.48	-22	-29.3	0.034	-8	0.077	-33	1.65
0.6	0.15	-1	19.6	9.58	-27	-29.1	0.035	-11	0.059	-38	1.61
0.7	0.16	-3	19.8	9.75	-31	-29.5	0.034	-14	0.069	-44	1.61
0.8	0.16	-5	19.9	9.93	-36	-29.9	0.032	-14	0.080	-56	1.67
0.9	0.17	-7	20.1	10.12	-41	-30.2	0.031	-15	0.087	-74	1.67
1.0	0.17	-10	20.3	10.31	-46	-30.2	0.031	-15	0.097	-90	1.65
1.1	0.18	-13	20.4	10.53	-52	-30.3	0.030	-16	0.104	-103	1.66
1.2	0.18	-16	20.6	10.75	-57	-30.6	0.030	-19	0.115	-111	1.62
1.3	0.18	-20	20.8	10.96	-63	-30.9	0.029	-20	0.136	-123	1.64
1.4	0.18	-23	21.0	11.16	-69	-31.2	0.027	-20	0.160	-131	1.70
1.5	0.18	-26	21.1	11.29	-76	-31.5	0.026	-21	0.190	-140	1.72
1.6	0.18	-32	21.1	11.39	-82	-31.6	0.026	-22	0.212	-154	1.70
1.7	0.18	-39	21.3	11.56	-89	-31.9	0.025	-25	0.217	-159	1.73
1.8	0.18	-45	21.3	11.68	-95	-32.3	0.024	-27	0.237	-166	1.76
1.9	0.17	-50	21.4	11.75	-103	-32.8	0.023	-29	0.256	-172	1.81
2.0	0.17	-55	21.4	11.76	-110	-33.1	0.022	-30	0.270	-178	1.87
2.1	0.18	-61	21.3	11.65	-118	-33.6	0.021	-34	0.284	178	1.94
2.2	0.18	-64	21.1	11.37	-125	-34.1	0.020	-36	0.303	172	2.04
2.3	0.18	-67	20.9	11.04	-132	-34.7	0.018	-39	0.318	166	2.28
2.4	0.19	-69	20.6	10.73	-140	-35.2	0.017	-43	0.326	160	2.44
2.5	0.20	-73	20.3	10.33	-147	-35.7	0.016	-48	0.326	156	2.66
2.6	0.20	-74	19.9	9.85	-154	-36.3	0.015	-54	0.330	152	2.95
2.7	0.20	-77	19.5	9.39	-161	-37.1	0.014	-63	0.331	147	3.29
2.8	0.21	-79	19.0	8.92	-167	-38.0	0.013	-73	0.331	142	3.69
2.9	0.21	-84	18.6	8.50	-173	-39.1	0.011	-83	0.325	138	4.57
3.0	0.22	-87	18.1	8.03	-180	-39.8	0.010	-96	0.314	134	5.32
3.1	0.22	-92	17.6	7.59	17	-40.8	0.009	-113	0.305	130	6.29
3.2	0.23	-96	17.1	7.19	169	-41.5	0.008	-130	0.293	126	7.48
3.3	0.25	-101	16.6	6.78	163	-41.6	0.008	-143	0.277	122	7.93
3.4	0.26	-106	16.1	6.39	158	-41.0	0.009	-153	0.262	119	7.51
3.5	0.27	-109	15.6	6.02	153	-39.5	0.011	-162	0.249	116	6.53
3.6	0.28	-112	15.1	5.69	148	-37.8	0.013	-172	0.234	112	5.86
3.7	0.30	-115	14.6	5.37	143	-36.6	0.015	-178	0.217	109	5.36
3.8	0.31	-118	14.1	5.07	139	-35.3	0.017	178	0.201	106	5.02
3.9	0.31	-120	13.6	4.80	134	-33.7	0.021	174	0.188	102	4.32
4.0	0.32	-122	13.2	4.55	130	-32.3	0.024	170	0.173	98	3.99
4.1	0.33	-125	12.7	4.32	126	-31.3	0.027	165	0.158	94	3.74
4.2	0.34	-128	12.2	4.09	122	-30.2	0.031	163	0.144	89	3.43
4.3	0.34	-131	11.8	3.89	118	-29.2	0.035	160	0.130	84	3.22
4.4	0.35	-135	11.4	3.70	114	-28.1	0.039	156	0.117	77	3.03
4.5	0.35	-138	10.9	3.52	110	-27.3	0.043	154	0.104	71	2.91
4.6	0.36	-142	10.5	3.35	106	-26.5	0.047	151	0.093	63	2.78
4.7	0.37	-146	10.1	3.19	103	-25.7	0.052	148	0.083	55	2.63
4.8	0.37	-149	9.6	3.04	99	-25.1	0.055	146	0.075	46	2.62
4.9	0.38	-152	9.3	2.90	96	-24.3	0.061	143	0.070	36	2.46
5.0	0.39	-156	8.9	2.77	93	-23.6	0.066	141	0.066	24	2.37

**Note:**

5. Reference plane per Figure 15 in Applications Information section.

## INA-34063 Applications Information

### Introduction

The INA-34063 is a +3 volt silicon RFIC amplifier that is designed with a two stage internal network to provide a broadband gain and 50  $\Omega$  input and output impedance. With a P-1 dB compressed output power of 8 dBm and noise figure of 4.5 dB at 1900 MHz, the INA-34063 is well suited for amplifier applications in mobile communication.

A feature of the INA-34063 is a positive gain slope over the 1–2 GHz range that is useful in many satellite-based TV and datacom systems.

In addition to use in TV delivery systems, the INA-34063 will find many applications in battery operated wireless communication systems.

### Operating Details

The INA-34063 is a voltage-biased device that operates from a +3 volt power supply with a typical current drain of 30 mA. All bias regulation circuitry is integrated into the RFIC.

Figure 10 shows a typical implementation of the INA-34063. The supply voltage for the INA-34063 must be applied to two terminals, the  $V_d$  pin and the RF Output pin.

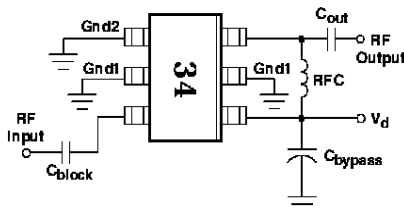


Figure 10. Basic Amplifier Application.

The  $V_d$  connection to the amplifier is RF bypassed by placing a capacitor to ground near the  $V_d$  pin of the amplifier package.

The power supply connection to the RF Output pin is achieved by means of a RF choke (inductor). The value of the RF choke must be large relative to 50  $\Omega$  in order to prevent loading of the RF Output. The supply voltage end of the RF choke is bypassed to ground with a capacitor. If the physical layout permits, this can be the same bypass capacitor that is used at the  $V_d$  terminal of the amplifier.

Blocking capacitors are normally placed in series with the RF Input and the RF Output to isolate the DC voltages on these pins from circuits adjacent to the amplifier. The values for the blocking and bypass capacitors are selected to provide a reactance at the lowest frequency of operation that is small relative to 50  $\Omega$ .

### Example Layout for 50 $\Omega$ Output Amplifier

An example layout for an amplifier using the INA-34063 with 50  $\Omega$  input and 50  $\Omega$  output is shown in Figure 11.

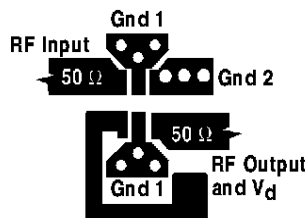


Figure 11. RF Layout.

This example uses a microstripline design (solid groundplane on the backside of the circuit board). The circuit board material is 0.031-inch thick FR-4. Plated through holes (vias)

are used to bring the ground to the topside of the circuit where needed. The performance of INA-34063 is sensitive to ground path inductance. The two-stage design creates the possibility of a feedback loop being formed through the ground returns of the stages, Gnd 1 and Gnd 2.

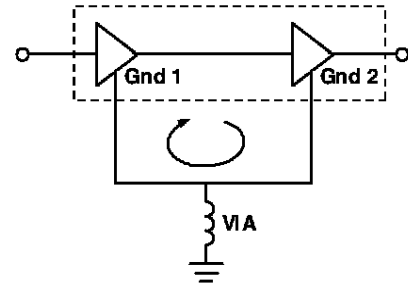


Figure 12. INA-34063 Potential Ground Loop.

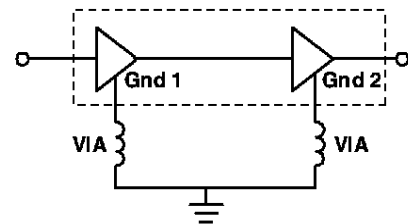


Figure 13. INA-34063 Suggested Layout.

At least one ground via should be placed adjacent to each ground pin to assure good RF grounding. Multiple vias are used to reduce the inductance of the path to ground and should be placed as close to the package terminals as practical.

The effects of the potential ground loop shown in Figure 12 may be observed as a “peaking” in the gain versus frequency response, an increase in input VSWR, or even as return gain at the input of the INA-34063.

Figure 14 shows an assembled amplifier. The +3 volt supply is fed directly into the  $V_d$  pin of the

INA-34063 and into the RF Output pin through the RF choke (RFC). Capacitor C3 provides RF bypassing for both the  $V_d$  pin and the power supply end of the RFC. Capacitor C4 is optional and may be used to add additional bypassing for the  $V_d$  line. A well-bypassed  $V_d$  line is especially necessary in cascades of amplifier stages to prevent oscillation that may occur as a result of RF feedback through the power supply lines.

For this demonstration circuit, the value chosen for the RF choke was 120 nH (Coilcraft 1008CS-221, TOKO LL2012-F or equivalent). All of the blocking and bypass capacitors are 100 pF. The gap in the output transmission line was bridged using copper foil cut to size. These values provide excellent amplifier performance from under 50 MHz through 2.4 GHz. Larger values for the choke and capacitors can be used to extend the lower end of the bandwidth. Since the gain of the INA-34063 extends down to DC, the frequency response of the amplifier is limited only by the values of the capacitors and choke.

A convenient method for making RF connection to the demonstration board is to use a PCB mounting type of SMA connector (Johnson 142-0701-881, or equivalent). These connectors can be slipped over the edge of the PCB and the center conductor soldered to the input and output lines. The ground pins of the connectors can be soldered to the ground plane on the backside of board.

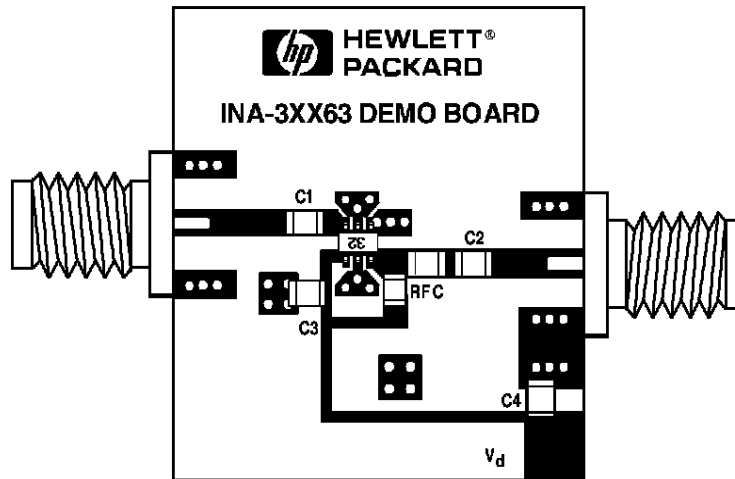


Figure 14. Assembled Amplifier.

### PCB Materials

Typical choices for PCB material for low cost wireless applications are FR-4 or G-10 with a thickness of 0.025 (0.635 mm) or 0.031 inches (0.787 mm). A thickness of 0.062 inches (1.574 mm) is the maximum that is recommended for use with this particular device. The use of a thicker board material increases the inductance of the plated through vias used for RF grounding and may deteriorate circuit performance. Adequate grounding is needed not only to obtain maximum amplifier performance but also to reduce any possibility of instability.

### Phase Reference Planes

The positions of the reference planes used to measure S-Parameters for this device are shown in Figure 15. As seen in the illustration, the reference planes are located at the point where the package leads contact the test circuit.

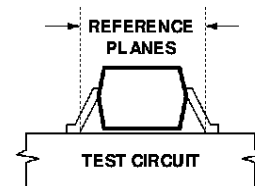


Figure 15. Phase Reference Planes.

### SOT-363 PCB Layout

The INA-34063 is packaged in the miniature SOT-363 (SC-70) surface mount package. A PCB pad layout for the SOT-363 package is shown in Figure 16 (dimensions are in inches). This layout provides ample allowance for package placement by automated assembly equipment without adding pad parasitics that could impair the high frequency performance of the INA-34063. The layout that is shown with a nominal SOT-363 package footprint superimposed on the PCB pads for reference.

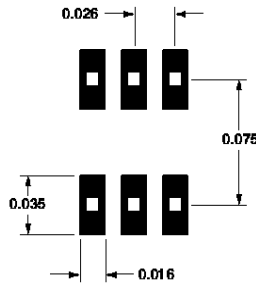


Figure 16. PCB Pad Layout for INA-32063 (dimensions in inches).

## Statistical Parameters

Several categories of parameters appear within this data sheet. Parameters may be described with values that are either “minimum or maximum,” “typical,” or “standard deviations.” The values for parameters are based on comprehensive product characterization data, in which automated measurements are made on a large number of parts taken from 3 non-consecutive process lots of semiconductor wafers. The data derived from product characterization tends to be normally distributed, e.g., fits the standard “bell curve.”

Parameters considered to be the most important to system performance are bounded by minimum or maximum values. For the INA-34063, these parameters are: Power Gain ( $|S_{21}|^2$ ) and the Device Current ( $I_D$ ). Each of these guaranteed parameters is 100% tested. Values for most of the parameters in the table of Electrical Specifications that are described by typical data are the mathematical mean ( $\mu$ ), of the normal distribution taken from the characterization data. For parameters where measurements

or mathematical averaging may not be practical, such as S-parameters or Noise Parameters and the performance curves, the data represents a nominal part taken from the “center” of the characterization distribution. Typical values are intended to be used as a basis for electrical design.

To assist designers in optimizing not only the immediate circuit using the INA-34063, but to also optimize and evaluate trade-off that affect a complete wireless system, the standard deviation ( $\sigma$ ) is provided for many of the Electrical Specifications parameters (at 25°C) in addition to the mean. The standard deviation is a measure of the variability about the mean. It will be recalled that a normal distribution is completely described by the mean and standard deviation.

Standard statistics tables or calculations provide the probability of a parameter falling between any two values, usually symmetrically located about the mean. Referring to Figure 17 for example, the probability of a parameter being between  $\pm 1\sigma$  is 68.3%; between  $\pm 2\sigma$  is 95.4%; and between  $\pm 3\sigma$  is 99.7%.

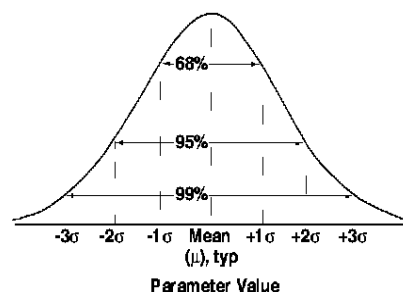


Figure 17. Normal Distribution.

## SMT Assembly

Reliable assembly of surface mount components is a complex process that involves many material, process, and equipment factors, including: method of heating (e.g., IR or vapor phase reflow, wave soldering, etc.) circuit board material, conductor thickness and pattern, type of solder alloy, and the thermal conductivity and thermal mass of components. Components with a low mass, such as the SOT-363 package, will reach solder reflow temperatures faster than those with a greater mass.

The INA-34063 has been qualified to the time-temperature profile shown in Figure 18. This profile is representative of an IR reflow type of surface mount assembly process.

After ramping up from room temperature, the circuit board with components attached to it (held in place with solder paste) passes through one or more preheat zones. The preheat zones increase the temperature of the board and components to prevent thermal shock and begin evaporating solvents from the solder paste. The reflow zone briefly elevates the temperature sufficiently to produce a reflow of the solder.

The rates of change of temperature for the ramp-up and cool down zones are chosen to be low enough to not cause deformation of the board or damage to components due to thermal shock. These parameters are typical for a surface mount assembly

process for the INA-34063. As a general guideline, the circuit board and components should only be exposed to the minimum temperatures and times necessary to achieve a uniform reflow of solder.

For more information on mounting considerations for packaged microwave semiconductors please refer to Hewlett-Packard application note AN-A006.

### Electrostatic Sensitivity



RFICs are electrostatic discharge (ESD) sensitive devices.

Although the INA-34063 is robust in design, permanent damage may occur to these devices if they are subjected to high-energy electrostatic discharges. Electrostatic charges as high as several thousand volts (which readily accumulate on the

human body and on test equipment) can discharge without detection and may result in degradation in performance or failure. Electronic devices may be subjected to ESD damage in any of the following areas:

- Storage & handling
- Inspection & testing
- Assembly
- In-circuit use

The INA-34063 is an ESD Class 1 device. Therefore, proper ESD precautions are recommended when handling, inspecting, and assembling these devices to avoid damage.

For more information on Electrostatic Discharge and Control refer to Hewlett-Packard application note AN-A004R.

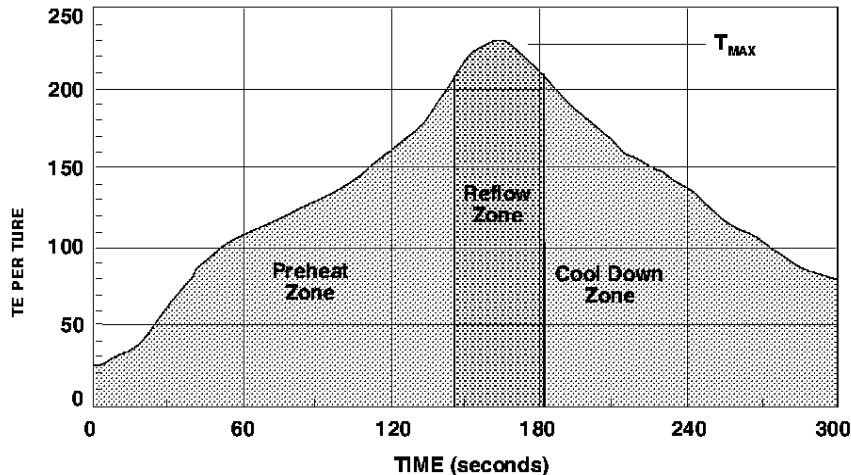
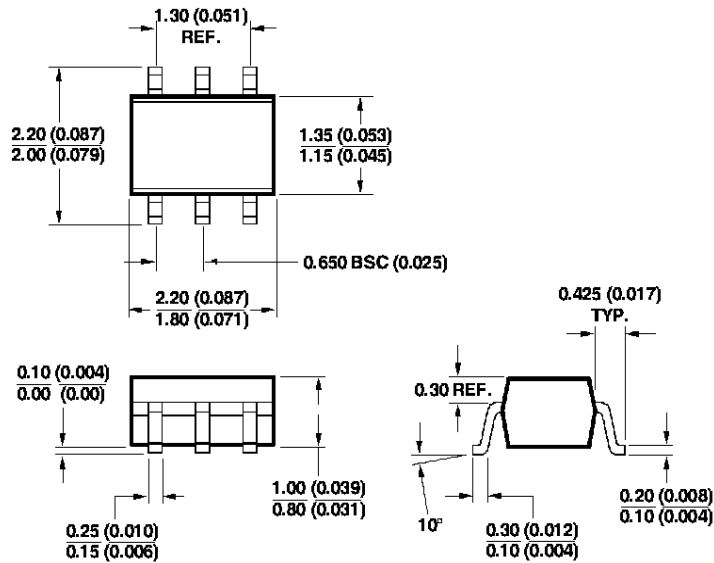


Figure 18. Surface Mount Assembly Profile.



## Package Dimensions

Outline 63 (SOT-363/SC-70)



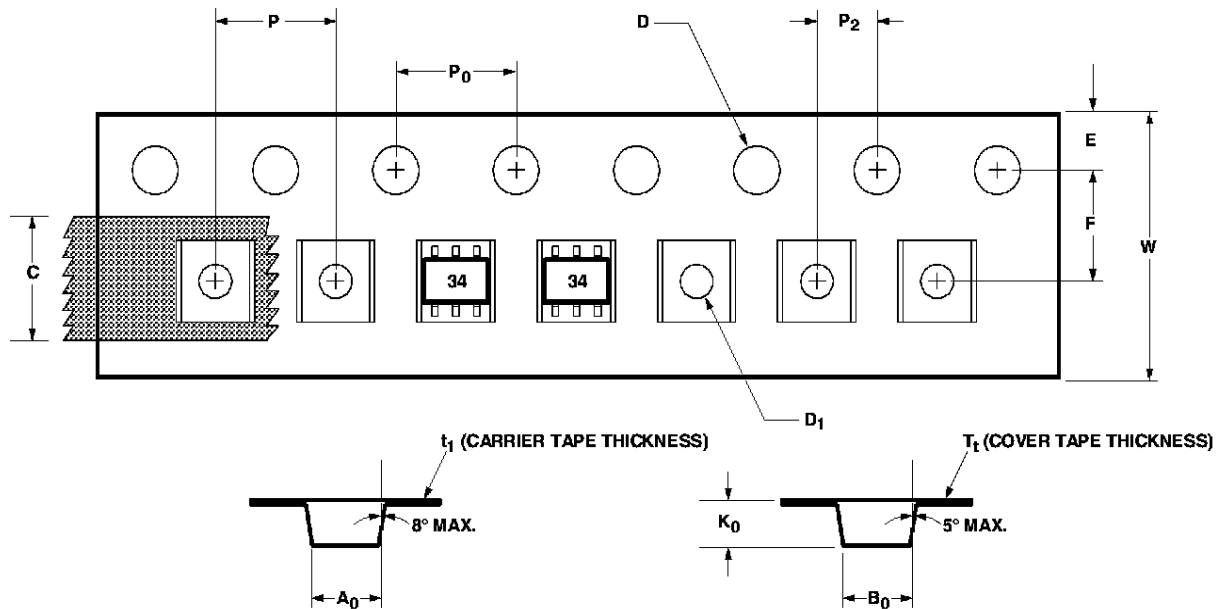
DIMENSIONS ARE IN MILLIMETERS (INCHES)

## INA-34063 Part Number Ordering Information

Part Number	Devices per Container	Container
INA-34063-BLK	100	tape strip in antistatic bag
INA-34063-TR1	3,000	7" reel
INA-34063-TR2	10,000	13" reel

## Tape Dimensions and Product Orientation

For Outline 63



DESCRIPTION		SYMBOL	SIZE (mm)	SIZE (INCHES)
CAVITY	LENGTH	$A_0$	$2.24 \pm 0.10$	$0.088 \pm 0.004$
	WIDTH	$B_0$	$2.34 \pm 0.10$	$0.092 \pm 0.004$
	DEPTH	$K_0$	$1.22 \pm 0.10$	$0.048 \pm 0.004$
	PITCH	$P$	$4.00 \pm 0.10$	$0.157 \pm 0.004$
	BOTTOM HOLE DIAMETER	$D_1$	$1.00 \pm 0.25$	$0.039 \pm 0.010$
PERFORATION	DIAMETER	$D$	$1.55 \pm 0.05$	$0.061 \pm 0.002$
	PITCH	$P_0$	$4.00 \pm 0.10$	$0.157 \pm 0.004$
	POSITION	$E$	$1.75 \pm 0.10$	$0.069 \pm 0.004$
CARRIER TAPE	WIDTH	$W$	$8.00 \pm 0.30$	$0.315 \pm 0.012$
	THICKNESS	$t_1$	$0.255 \pm 0.013$	$0.010 \pm 0.0005$
COVER TAPE	WIDTH	$C$	$5.4 \pm 0.10$	$0.205 \pm 0.004$
	TAPE THICKNESS	$T_t$	$0.062 \pm 0.001$	$0.0025 \pm 0.00004$
DISTANCE	CAVITY TO PERFORATION (WIDTH DIRECTION)	$F$	$3.50 \pm 0.05$	$0.138 \pm 0.002$
	CAVITY TO PERFORATION (LENGTH DIRECTION)	$P_2$	$2.00 \pm 0.05$	$0.079 \pm 0.002$

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